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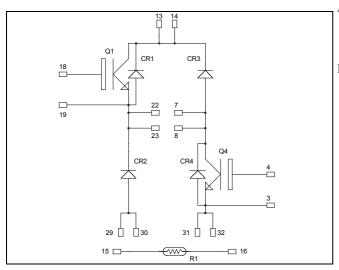




Asymmetrical - Bridge NPT IGBT Power Module

$$V_{CES} = 1200V$$

 $I_{C} = 50A$ @ $Tc = 80$ °C

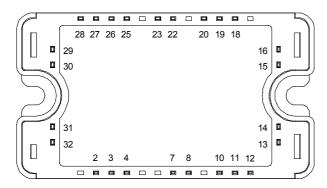


Application

- AC and DC motor control
- Switched Mode Power Supplies

Features

- Non Punch Through (NPT) Fast IGBT
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 50 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
 - Symmetrical design
- Kelvin emitter for easy drive
- Very low stray inductance
- High level of integration
- Internal thermistor for temperature monitoring



All multiple inputs and outputs must be shorted together Example: 13/14; 29/30; 22/23 ...

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- Easy paralleling due to positive TC of VCEsat
- RoHS compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		1200	V
$I_{\rm C}$	Continuous Collector Current	$T_c = 25^{\circ}C$	70	
	Continuous Conector Current	$T_c = 80$ °C	50	A
I_{CM}	Pulsed Collector Current	$T_c = 25^{\circ}C$	150	
V_{GE}	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_c = 25$ °C	312	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150^{\circ}C$	100A @ 1200V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
Ţ	Zero Gate Voltage Collector Current	$V_{GE} = 0V$	$T_i = 25^{\circ}C$			250	μA
I_{CES}	Zero Gate Voltage Collector Current	$V_{CE} = 1200V$	$T_{i} = 125^{\circ}C$			500	μΑ
17	Callantan Emittan action tion Waltana	$V_{GE} = 15V$	$T_j = 25$ °C		3.2	3.7	V
$V_{CE(sat)}$	Collector Emitter saturation Voltage	$I_C = 50A$	$T_j = 125$ °C		4.0		V
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 1 \text{ mA}$		4.5		6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20 \text{ V}, V_{CE} = 0 \text{ V}$				100	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	1	Min	Тур	Max	Unit
C_{ies}	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$			3450		pF
C_{oes}	Output Capacitance				330		
C_{res}	Reverse Transfer Capacitance	f = 1MHz			220		
Q_{g}	Total gate Charge	$V_{GS} = 15V$			330		nC
Q_{ge}	Gate – Emitter Charge	$V_{Bus} = 600V$			35		
Q_{gc}	Gate – Collector Charge	$I_C = 50A$			200		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switch	hing (25°C)		35		ns
$T_{\rm r}$	Rise Time	$V_{GE} = 15V$			65		
$T_{d(off)}$	Turn-off Delay Time	$V_{\text{Bus}} = 600V$ $I_{\text{C}} = 50A$			320		
T_{f}	Fall Time	$R_G = 5 \Omega$			30		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = \pm 15V$ $V_{Bus} = 600V$ $I_{C} = 50A$ $R_{G} = 5 \Omega$			35		ns
$T_{\rm r}$	Rise Time				65		
$T_{d(off)}$	Turn-off Delay Time				360		
$T_{\rm f}$	Fall Time				40		
Eon	Turn-on Switching Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$	$T_j = 125$ °C		6.9		.mo I
E_{off}	Turn-off Switching Energy	$I_C = 50A$ $R_G = 5 \Omega$	$T_j = 125$ °C		3.05		mJ
I_{sc}	Short Circuit data	$V_{GE} \le 15V ; V_{Bus}$ $t_p \le 10 \mu s ; T_j = 1$			300		A

Diode ratings and characteristics (CR2 & CR3)

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V
I_{RM}	Maximum Reverse Leakage Current	$V_R=1200V$ $T_j=$	$T_j = 25$ °C			100	μA
1RM		VR 1200 V	$T_j = 125$ °C			500	μ2ι
I_F	DC Forward Current		$Tc = 80^{\circ}C$		60		A
	Diode Forward Voltage	$I_F = 60A$			2.5	3	
V_{F}		$I_F = 120A$			3		V
		$I_F = 60A$	$T_j = 125$ °C		1.8		
+	Reverse Recovery Time	$I_F = 60A$ $V_R = 800V$	$T_j = 25$ °C		265		ns
t_{rr}			$T_j = 125$ °C		350		113
Q _{rr}	Reverse Recovery Charge		$T_j = 25$ °C		560		пC
				2890		пС	

CR1 & CR4 are IGBT protection diodes only



Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance		IGBT			0.4	°C/W
KthJC			Diode			0.9	C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range		-40		125	°C	
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight					110	g

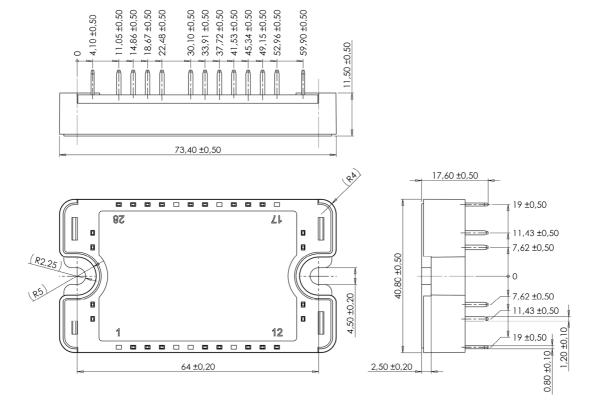
Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic		Min	Typ	Max	Unit
R ₂₅	Resistance @ 25°C			50		kΩ
$\Delta R_{25}/R_{25}$				5		%
$B_{25/85}$	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta \mathrm{B/B}$		T _C =100°C		4		%

$$R_T = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{75}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$

$$R_T: \text{ Thermistor value at T}$$

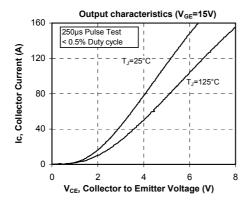
SP3 Package outline (dimensions in mm)

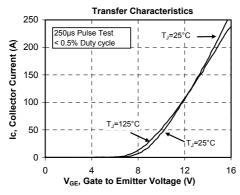


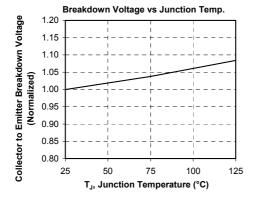
See application note 1901 - Mounting Instructions for SP3 Power Modules on www.microsemi.com

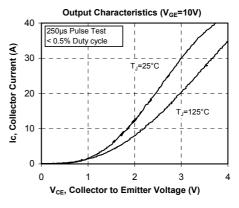


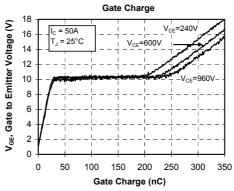
Typical IGBT Performance Curve

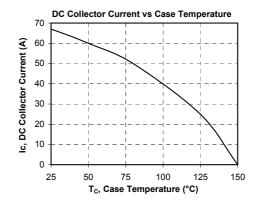






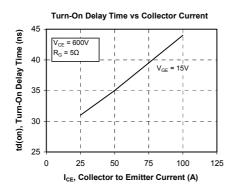


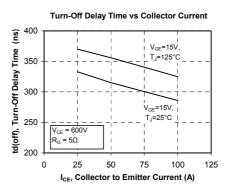


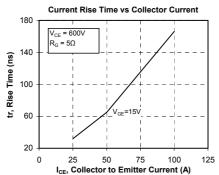


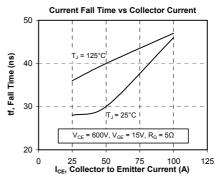
www.microsemi.com

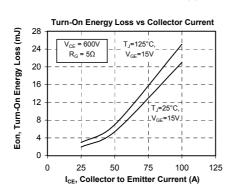


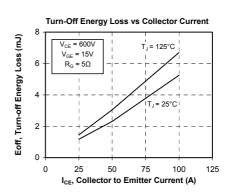


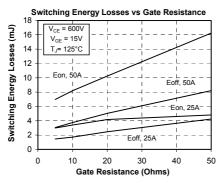


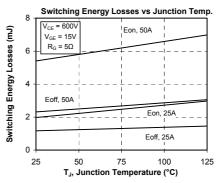








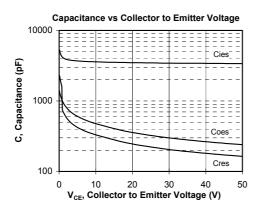


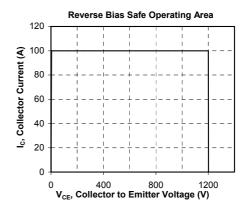


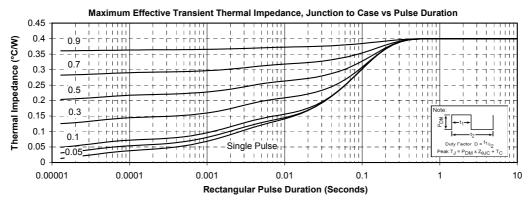
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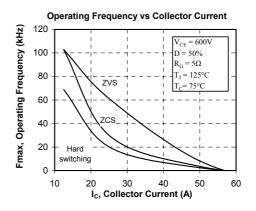
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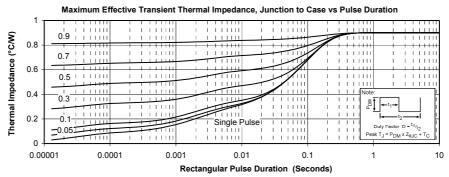


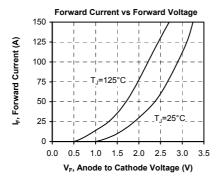


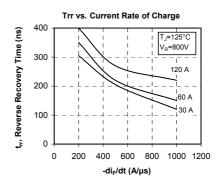
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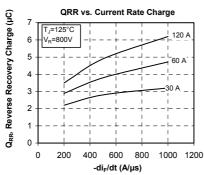


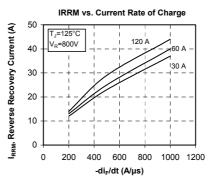
Typical diode Performance Curve

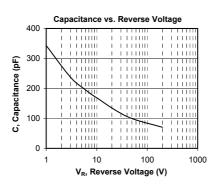


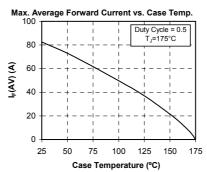












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